

Si/InAs Composite Channels: Low Effective Mass and Direct Bandgap Structures

Objective:

- Composite channels consist of Si/InAs QW of varying InAs widths.
- We aim to improve the Si effective mass and bandgap, Δ .

Approach:

- Consider 8nm QW: Si(8-x)nm/ InAs xnm and use NEMO-3D to compute dispersion relations and:
 - Calculate Δ as a function of x
 - Obtain the effective mass m^*

Result:

- Both Δ and m^* decrease as a function of InAs content, x

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